BAP64Q

Quad PIN diode attenuator

Rev. 2.1 — 1 February 2019 Product data sheet

1 Product profile

1.1 General description

Quad PIN diode in a SOT753 package.

1.2 Features and benefits

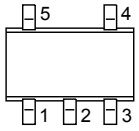
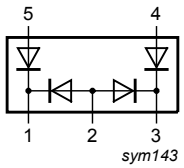
- 4 PIN diodes in a SOT753 package
- 300 kHz to 4 GHz
- High linearity
- Low insertion loss
- reduction in part count
- Low diode capacitance
- Low diode forward resistance

1.3 Applications

- RF attenuators
- Broadband system applications
- General-purpose Voltage Controlled Attenuators for high linearity applications

2 Pinning information

Table 1. Discrete pinning

Pin	Description		Simplified outline	Graphic symbol
1	RF in		 Top view	
2	series bias			
3	RF out			
4	shunt 1 bias			
5	shunt 2 bias			

3 Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BAP64Q	SC-74A	plastic surface-mounted package; 5 leads	SOT753

4 Marking

Table 3. Marking

Type number	Marking code
BAP64Q	A1

5 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_R	reverse voltage		[1]	-	100	V
I_F	forward current		[1]	-	100	mA
P_{tot}	total power dissipation	$T_{sp} \leq 90$ °C	[1]	-	125	mW
T_{stg}	storage temperature			-65	+150	°C
T_j	junction temperature			-65	+150	°C

[1] single diode.

6 Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		350	K/W

7 Characteristics

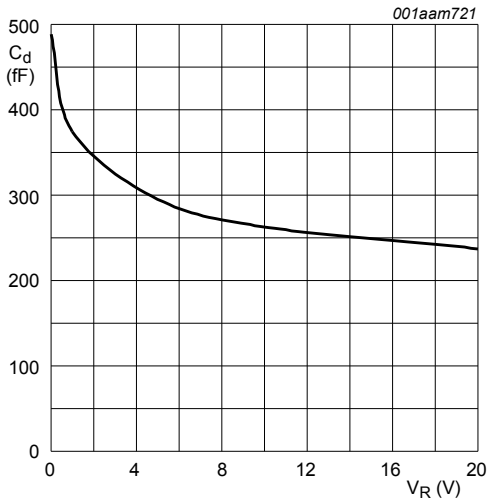
Table 6. Characteristics

T_j = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per diode							
V_F	forward voltage	I_F = 50 mA		-	0.95	1.1	V
I_R	reverse current	V_R = 60 V		-	-	10	µA
		V_R = 20 V		-	-	1	µA
C_d	diode capacitance	f = 1 MHz (see Figure 1)					
		V_R = 0 V		-	0.52	-	pF
		V_R = 1 V		-	0.37	-	pF
		V_R = 20 V		-	0.23	0.35	pF
r_D	diode forward resistance	f = 100 MHz (see Figure 2)					
		I_F = 0.5 mA	[1]	-	20	40	Ω
		I_F = 1 mA	[1]	-	10	20	Ω
		I_F = 10 mA	[1]	-	2	3.8	Ω
		I_F = 100 mA	[1]	-	0.7	1.35	Ω
τ_L	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω; measured at I_R = 3 mA		-	1.55	-	µs

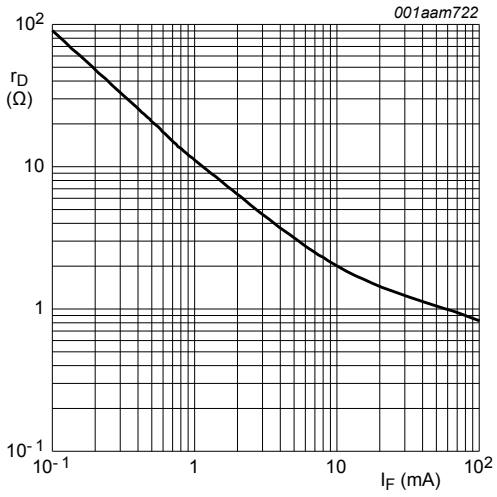
[1] Guaranteed on AQL basis: inspection level S4, AQL 1.0.

8 Graphical data



f = 1 MHz; T_j = 25 °C.

Figure 1. Diode capacitance as a function of reverse voltage (typical values)



f = 100 MHz; T_j = 25 °C.

Figure 2. Diode forward resistance as a function of forward current (typical values)

9 Application information

9.1 Application circuit

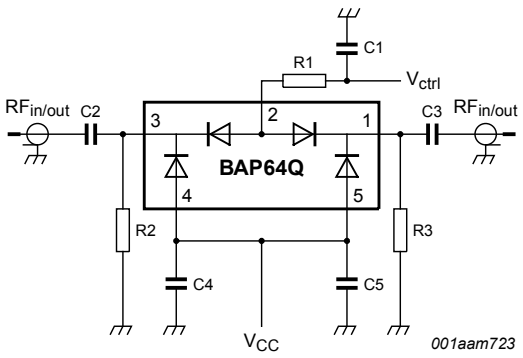


Figure 3. Wideband Quad PIN diode Π attenuator circuit

Table 7. List of components used for the typical application

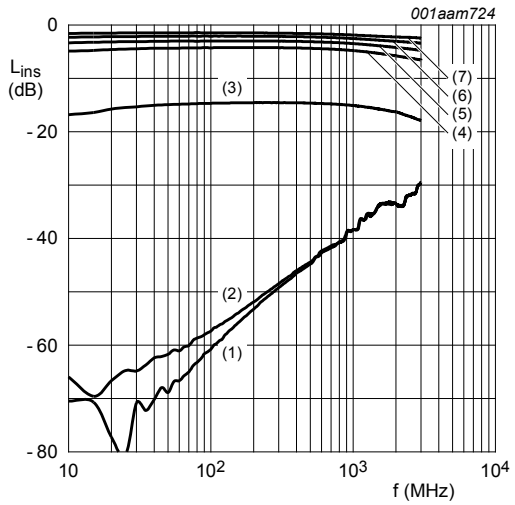
Component	Description	Value
C1; C2; C3; C4; C5	chip capacitor	10 nF
R1; R2; R3	chip resistor	1000 Ω

9.2 Quad PIN Π attenuator characteristics

Table 8. Typical performance for BAP64Q quad PIN diode Π attenuator

V_{CC} = 0.75 V; T_{amb} = 25 °C unless otherwise specified.

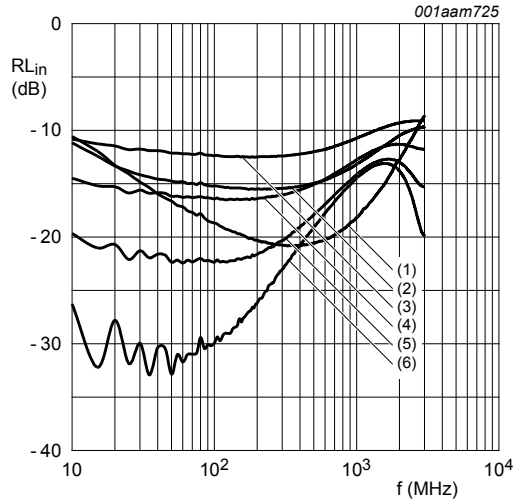
Symbol	Parameter	Test Conditions	Typ	Units
L_{ins}	insertion loss	V_{ctrl} = 10 V; f = 1 GHz	1.8	dB
RL_{in}	input return loss	V_{ctrl} = 0 V; f = 1 GHz	18	dB
α	attenuation	V_{ctrl} = 0 V; f = 1 GHz	38	dB
$IP3_i$	input third-order intercept point	f = 0.1 GHz		
		V_{ctrl} = 2 V	32	dBm
		V_{ctrl} = 10 V	42	dBm
		f = 0.9 GHz		
		V_{ctrl} = 2 V	40	dBm
		V_{ctrl} = 10 V	41	dBm
		f = 1.8 GHz		
		V_{ctrl} = 2 V	40	dBm
		V_{ctrl} = 10 V	37	dBm
		f = 2.1 GHz		
		V_{ctrl} = 2 V	38	dBm
		V_{ctrl} = 10 V	39	dBm



V_{CC} = 0.75 V; T_{amb} = 25 °C.

(1) V_{ctrl} = 0 V
(2) V_{ctrl} = 0.5 V
(3) V_{ctrl} = 1 V
(4) V_{ctrl} = 2 V
(5) V_{ctrl} = 3 V
(6) V_{ctrl} = 5 V
(7) V_{ctrl} = 10 V

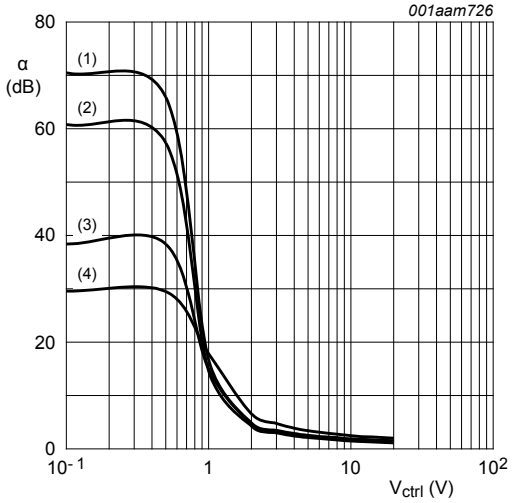
Figure 4. Insertion loss as function of frequency (typical values)



V_{CC} = 0.75 V; T_{amb} = 25 °C.

(1) V_{ctrl} = 0 V
(2) V_{ctrl} = 1 V
(3) V_{ctrl} = 2 V
(4) V_{ctrl} = 3 V
(5) V_{ctrl} = 5 V
(6) V_{ctrl} = 10 V

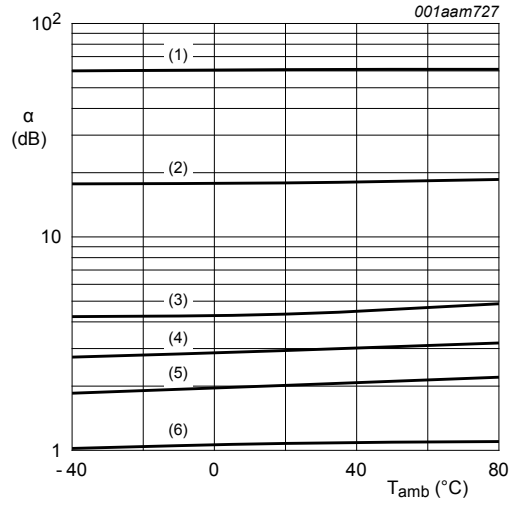
Figure 5. Return loss as function of frequency (typical values)



V_{CC} = 0.75 V; T_{amb} = 25 °C.

(1) f = 10 MHz
(2) f = 100 MHz
(3) f = 1000 MHz
(4) f = 3000 MHz

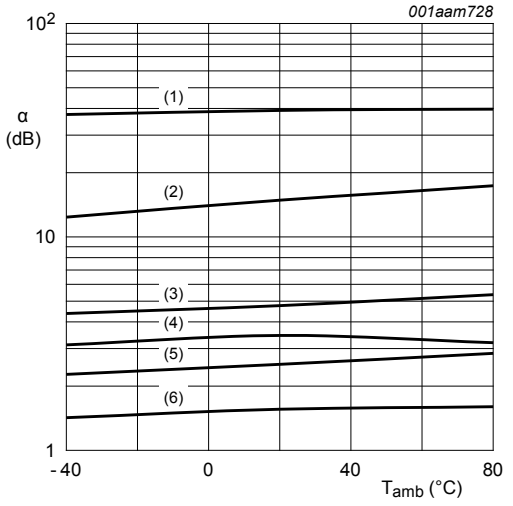
Figure 6. Attenuation as function of control voltage (typical values)



V_{CC} = 0.75 V; f = 100 MHz.

(1) V_{ctrl} = 0 V
(2) V_{ctrl} = 1 V
(3) V_{ctrl} = 2 V
(4) V_{ctrl} = 3 V
(5) V_{ctrl} = 5 V
(6) V_{ctrl} = 10 V

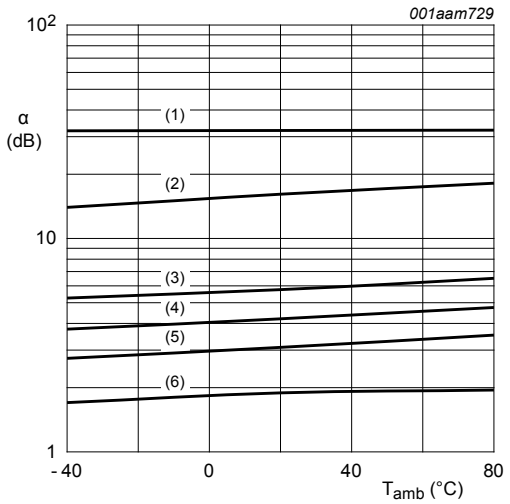
Figure 7. Attenuation as function of temperature (typical values)



V_{CC} = 0.75 V; f = 1000 MHz.

(1) V_{ctrl} = 0 V
(2) V_{ctrl} = 1 V
(3) V_{ctrl} = 2 V
(4) V_{ctrl} = 3 V
(5) V_{ctrl} = 5 V
(6) V_{ctrl} = 10 V

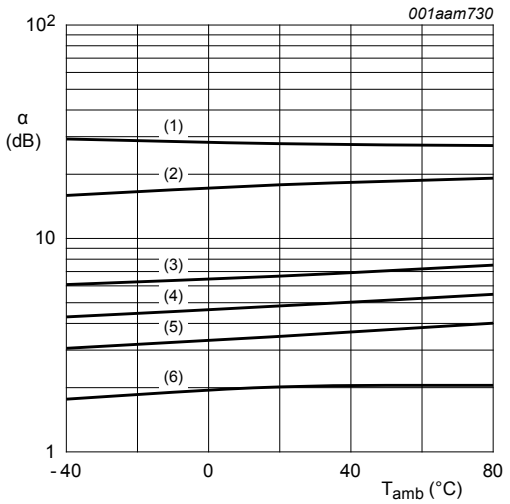
Figure 8. Attenuation as function of temperature (typical values)



V_{CC} = 0.75 V; f = 2000 MHz.

(1) V_{ctrl} = 0 V
(2) V_{ctrl} = 1 V
(3) V_{ctrl} = 2 V
(4) V_{ctrl} = 3 V
(5) V_{ctrl} = 5 V
(6) V_{ctrl} = 10 V

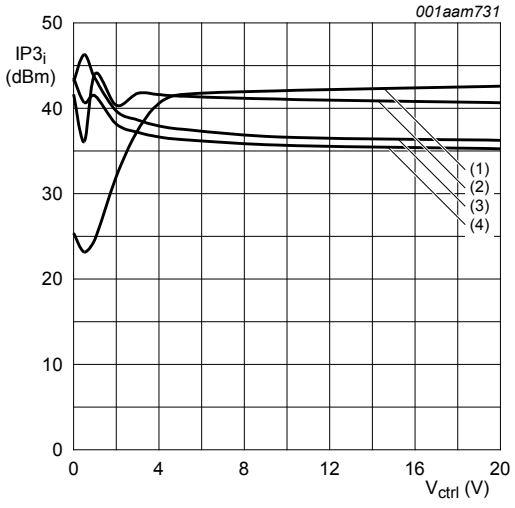
Figure 9. Attenuation as function of temperature (typical values)



V_{CC} = 0.75 V; f = 3000 MHz.

(1) V_{ctrl} = 0 V
(2) V_{ctrl} = 1 V
(3) V_{ctrl} = 2 V
(4) V_{ctrl} = 3 V
(5) V_{ctrl} = 5 V
(6) V_{ctrl} = 10 V

Figure 10. Attenuation as function of temperature (typical values)



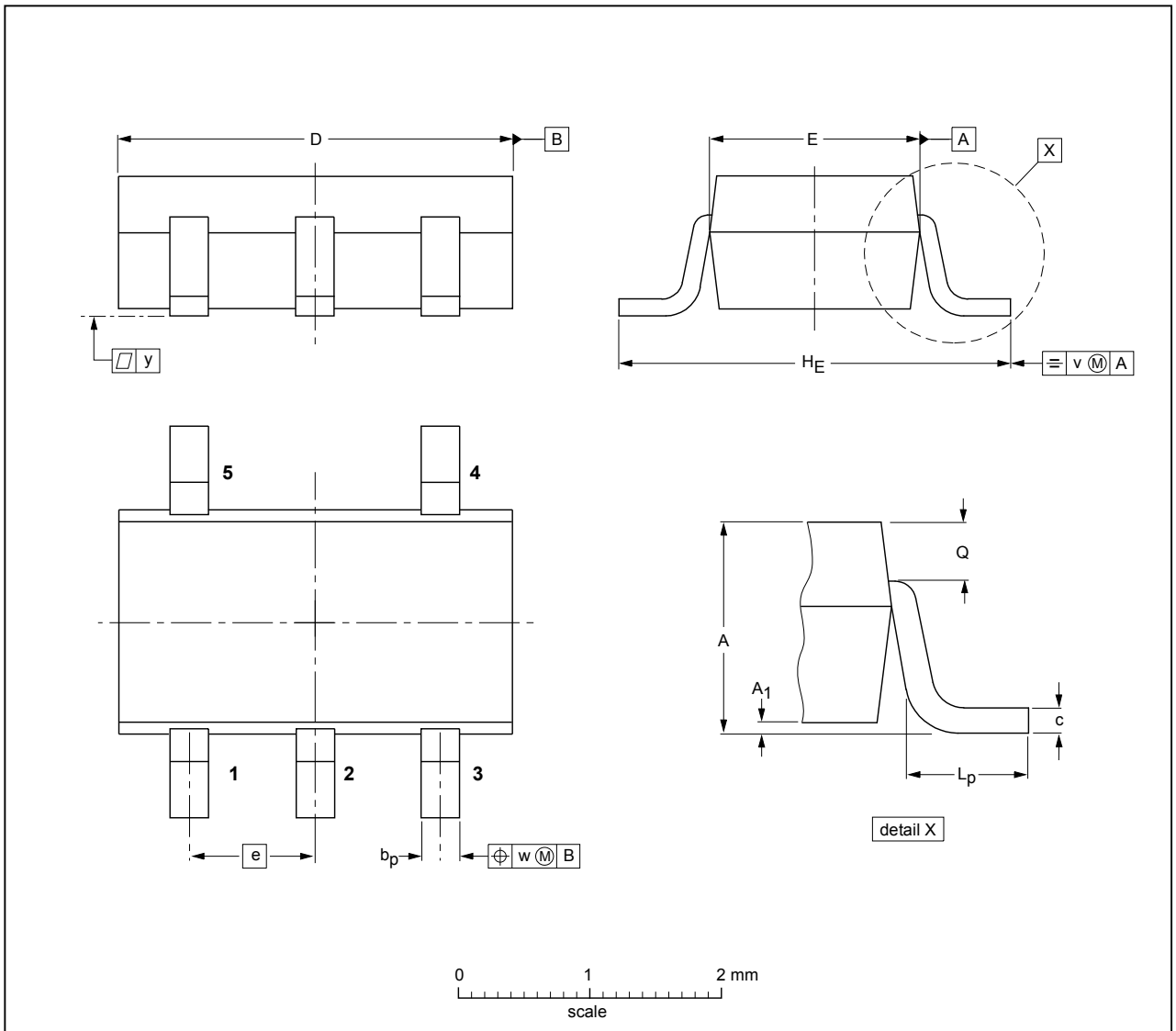
V_{CC} = 0.75 V; T_{amb} = 25 °C.

(1) f = 100 MHz
(2) f = 900 MHz
(3) f = 1800 MHz
(4) f = 2100 MHz

Figure 11. Input third-order intercept point as control voltage (typical values)

10 Package outline

Plastic surface-mounted package; 5 leads **SOT753**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b_p	c	D	E	e	H_E	L_p	Q	v	w	y
mm	1.1 0.9	0.100 0.013	0.40 0.25	0.26 0.10	3.1 2.7	1.7 1.3	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT753			SC-74A			~~02-04-16~~ 06-03-16

Figure 12. Package outline SOT753

11 Abbreviations

Table 9. Abbreviations

Acronym	Description
AQL	acceptable quality level
PIN	P-type, intrinsic, N-type
RF	radio frequency
S4	special inspection level 4

12 Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP64Q v.2.1	20190201	Product data sheet	-	BAP64Q v.2
Modifications:	• changed condition for reverse current for V_R from 100 V to 60 V			
BAP64Q v.2	20181213	Product data sheet	-	BAP64Q v.1
Modifications:	• The "Legal information" pages have been updated. • Adjusted Limiting Value P_{tot} to $T_{sp} \leq 90$ °C			
BAP64Q v.1	20101007	Product data sheet	-	-

13 Legal information

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".
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